

## Product Summary

$BV_{DSS}$	$R_{DS(ON)} \text{ Max}$	$I_D$ $T_C = +25^\circ\text{C}$ (Note 10)
60V	3.4mΩ @ $V_{GS} = 10\text{V}$	100A

## Description and Applications

This MOSFET has been designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

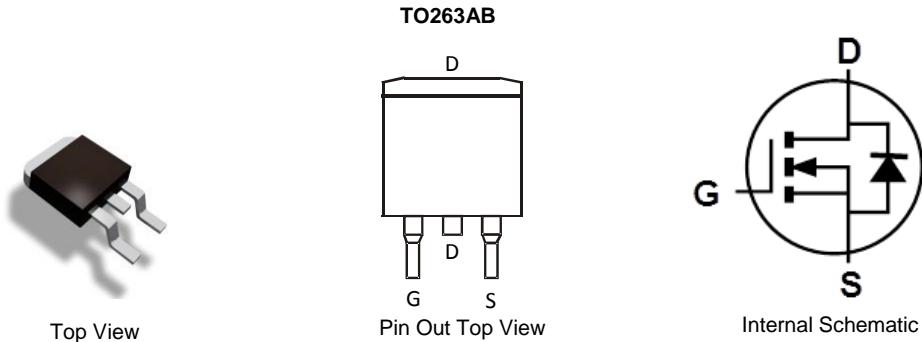
- Engine Management Systems
- Body Control Electronics
- DC-DC Converters

## Features

- Rated to  $+175^\circ\text{C}$  – Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching – Ensures More Reliable and Robust End Application
- Low  $R_{DS(ON)}$  – Minimizes Power Losses
- Low  $Q_g$  – Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

## Mechanical Data

- Case: TO263AB
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish - Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 1.7 grams (Approximate)



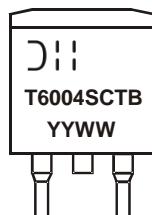
## Ordering Information (Note 5)

Part Number	Case	Packaging
DMTH6004SCTBQ-13	TO263AB	800 / Tape & Reel

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, For more information, please refer to [http://www.diodes.com/product\\_compliance\\_definitions.html](http://www.diodes.com/product_compliance_definitions.html).
5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



T6004SCTB = Product Type Marking Code  
 YYWW = Date Code Marking  
 YY = Last Two Digits of Year (ex: 15 = 2015)  
 WW = Week (01 to 53)

**Maximum Ratings** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$		60	V
Gate-Source Voltage	$V_{GSS}$		$\pm 20$	V
Continuous Drain Current (Note 7)	$T_C = +25^\circ\text{C}$ $T_C = +100^\circ\text{C}$	$I_D$	100 100	A
Maximum Continuous Body Diode Forward Current (Note 7)	$T_C = +25^\circ\text{C}$	$I_S$	100	A
Pulsed Drain Current (10 $\mu\text{s}$ Pulse, Duty Cycle=1%)		$I_{DM}$	200	A
Avalanche Current, $L=0.2\text{mH}$		$I_{AS}$	45	A
Avalanche Energy, $L=0.2\text{mH}$		$E_{AS}$	200	mJ

**Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 6)	$T_A = +25^\circ\text{C}$	$P_D$	4.7	W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	32	$^\circ\text{C}/\text{W}$
Total Power Dissipation (Note 7)	$T_C = +25^\circ\text{C}$	$P_D$	136	W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	1.1	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range		$T_J, T_{STG}$	-55 to +175	$^\circ\text{C}$

**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
<b>OFF CHARACTERISTICS (Note 8)</b>						
Drain-Source Breakdown Voltage	$BV_{DSS}$	60	—	—	V	$V_{GS} = 0\text{V}, I_D = 1\text{mA}$
Zero Gate Voltage Drain Current (Note 9)	$I_{DSS}$	—	—	1	$\mu\text{A}$	$V_{DS} = 48\text{V}, V_{GS} = 0\text{V}$
		—	—	100	$\mu\text{A}$	$V_{DS} = 48\text{V}, V_{GS} = 0\text{V}, T_J = 125^\circ\text{C}$
Gate-Source Leakage	$I_{GSS}$	—	—	$\pm 100$	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
<b>ON CHARACTERISTICS (Note 8)</b>						
Gate Threshold Voltage	$V_{GS(\text{TH})}$	2	—	4	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(\text{ON})}$	—	2.9	3.4	$\text{m}\Omega$	$V_{GS} = 10\text{V}, I_D = 100\text{A}$
Diode Forward Voltage	$V_{SD}$	—	—	1.3	V	$V_{GS} = 0\text{V}, I_S = 100\text{A}$
<b>DYNAMIC CHARACTERISTICS (Note 9)</b>						
Input Capacitance	$C_{iss}$	—	4,556	—	pF	$V_{DS} = 30\text{V}, V_{GS} = 0\text{V}$ $f = 1\text{MHz}$
Output Capacitance	$C_{oss}$	—	1,383	—		
Reverse Transfer Capacitance	$C_{rss}$	—	105.2	—	nC	$V_{DD} = 30\text{V}, I_D = 90\text{A},$ $V_{GS} = 10\text{V}$
Gate Resistance	$R_g$	0.1	0.66	1.9		
Total Gate Charge	$Q_g$	—	95.4	—	ns	$V_{DD} = 30\text{V}, V_{GS} = 10\text{V},$ $I_D = 90\text{A}, R_G = 3.5\Omega$
Gate-Source Charge	$Q_{qs}$	—	21.6	—		
Gate-Drain Charge	$Q_{qd}$	—	20.4	—	ns	$I_F = 50\text{A}, dI/dt = 100\text{A}/\mu\text{s}$
Turn-On Delay Time	$t_{D(\text{ON})}$	—	13.2	—		
Turn-On Rise Time	$t_R$	—	11.7	—	ns	$I_F = 50\text{A}, dI/dt = 100\text{A}/\mu\text{s}$
Turn-Off Delay Time	$t_{D(\text{OFF})}$	—	31	—		
Turn-Off Fall Time	$t_F$	—	12	—	ns	$I_F = 50\text{A}, dI/dt = 100\text{A}/\mu\text{s}$
Reverse Recovery Time	$t_{RR}$	—	50.5	—		
Reverse Recovery Charge	$Q_{RR}$	—	80.8	—	nC	

Notes: 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.

10. Package limited.

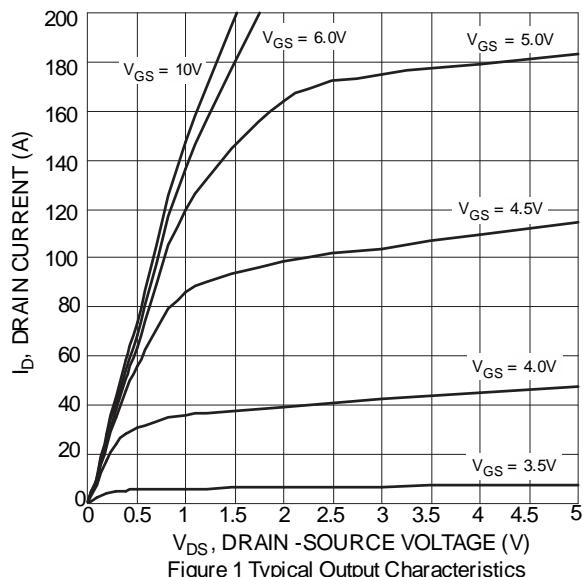


Figure 1 Typical Output Characteristics

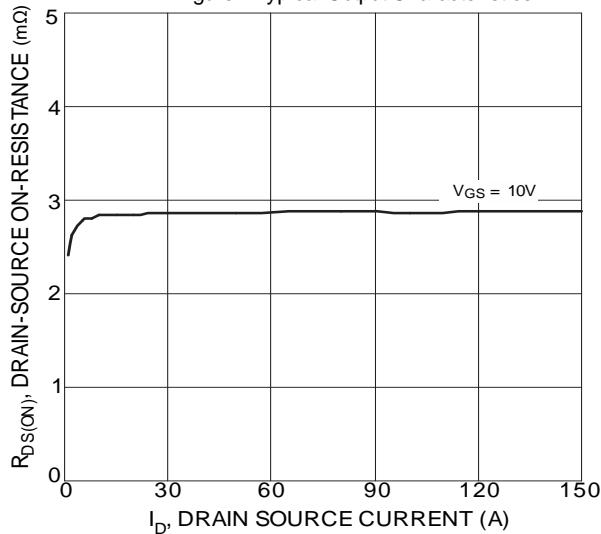


Figure 3 Typical On-Resistance vs.  
Drain Current and Gate Voltage

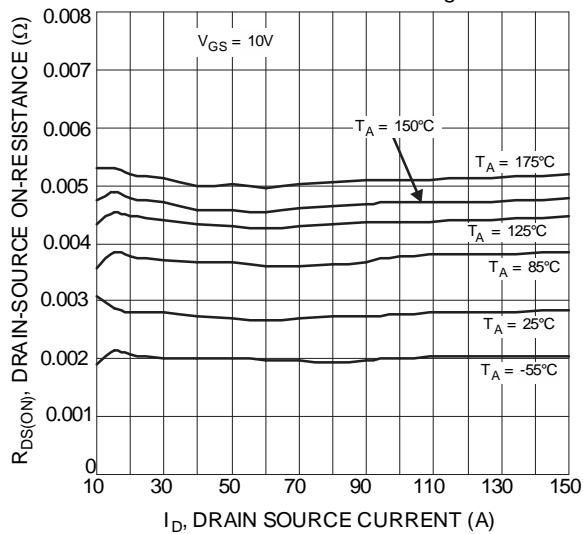


Figure 5 Typical On-Resistance vs.  
Drain Current and Temperature

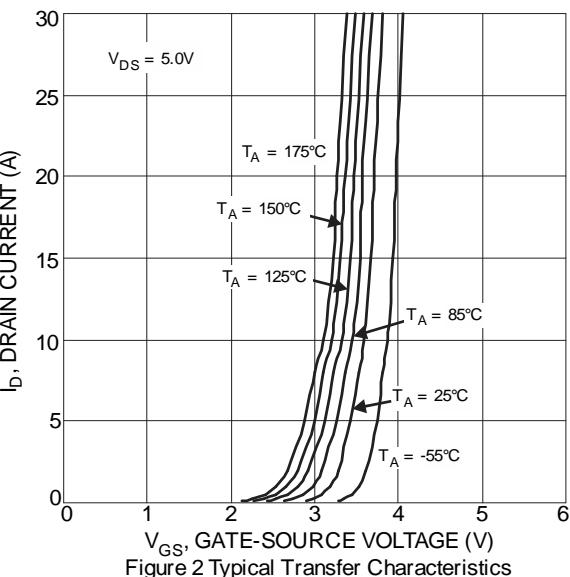


Figure 2 Typical Transfer Characteristics

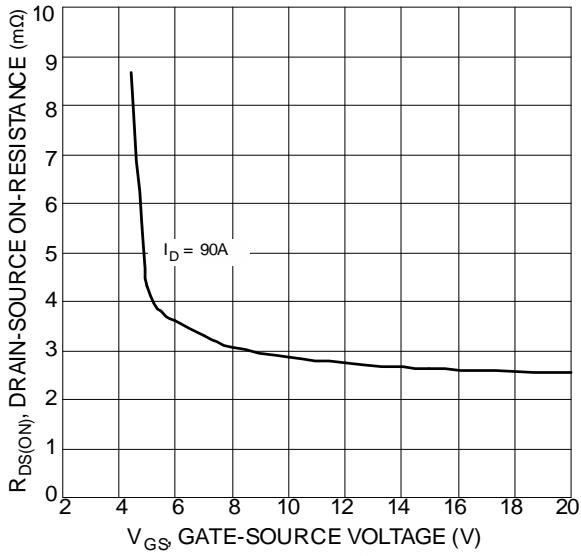


Figure 4 Typical Transfer Characteristic

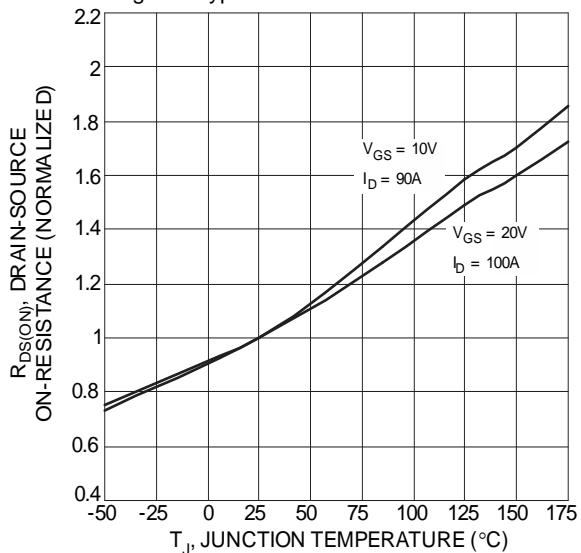
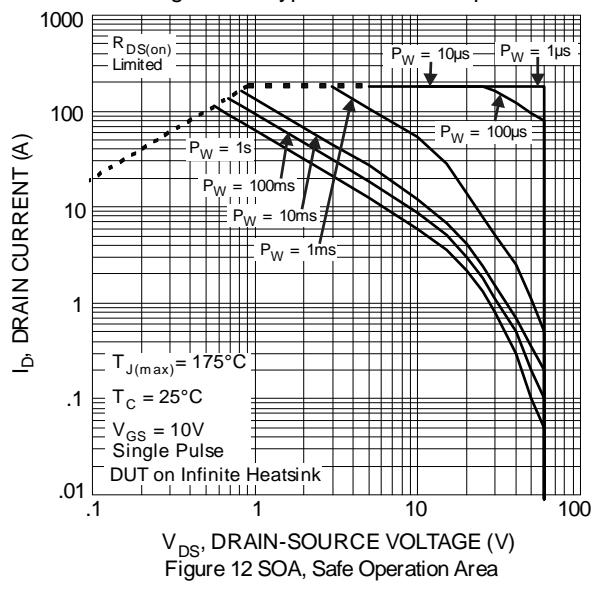
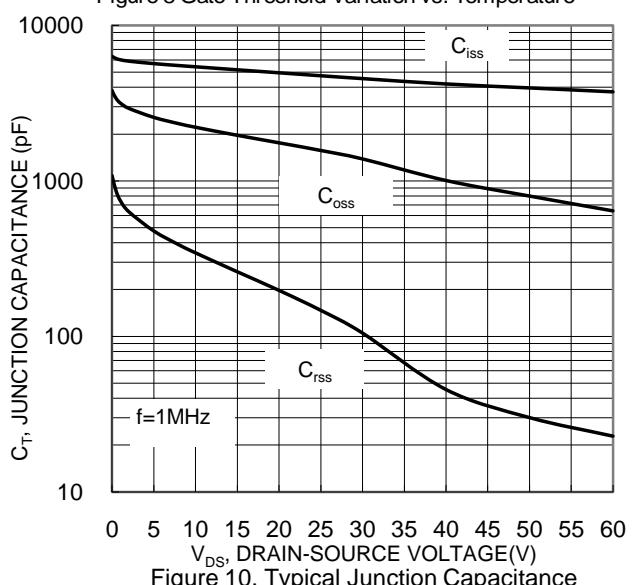
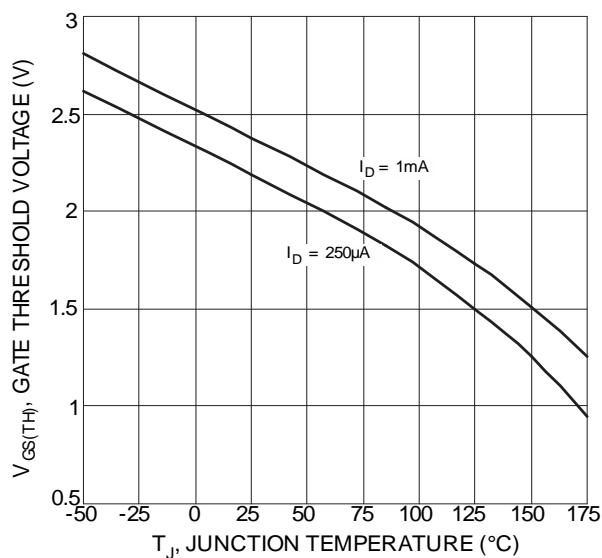
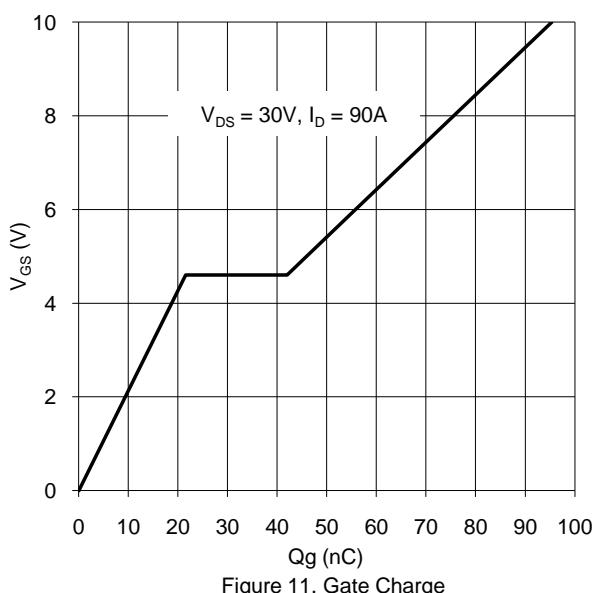
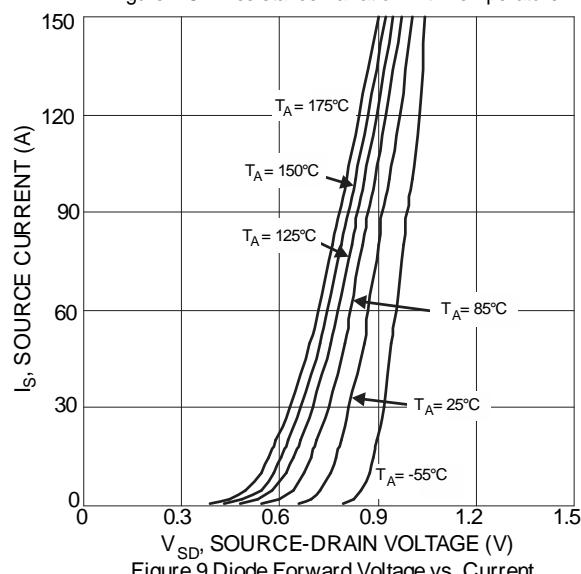
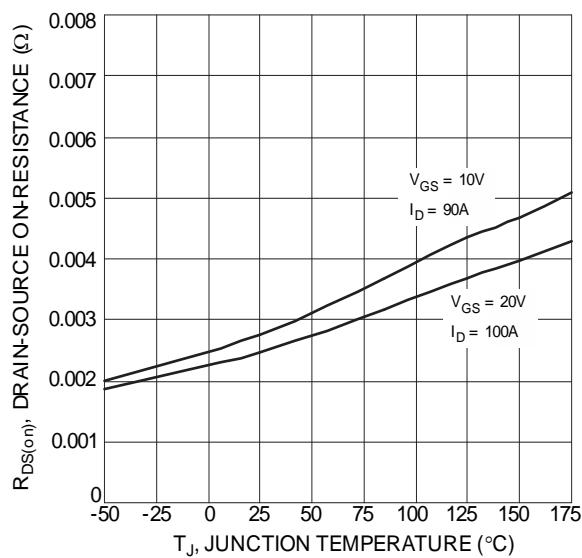


Figure 6 On-Resistance Variation with Temperature



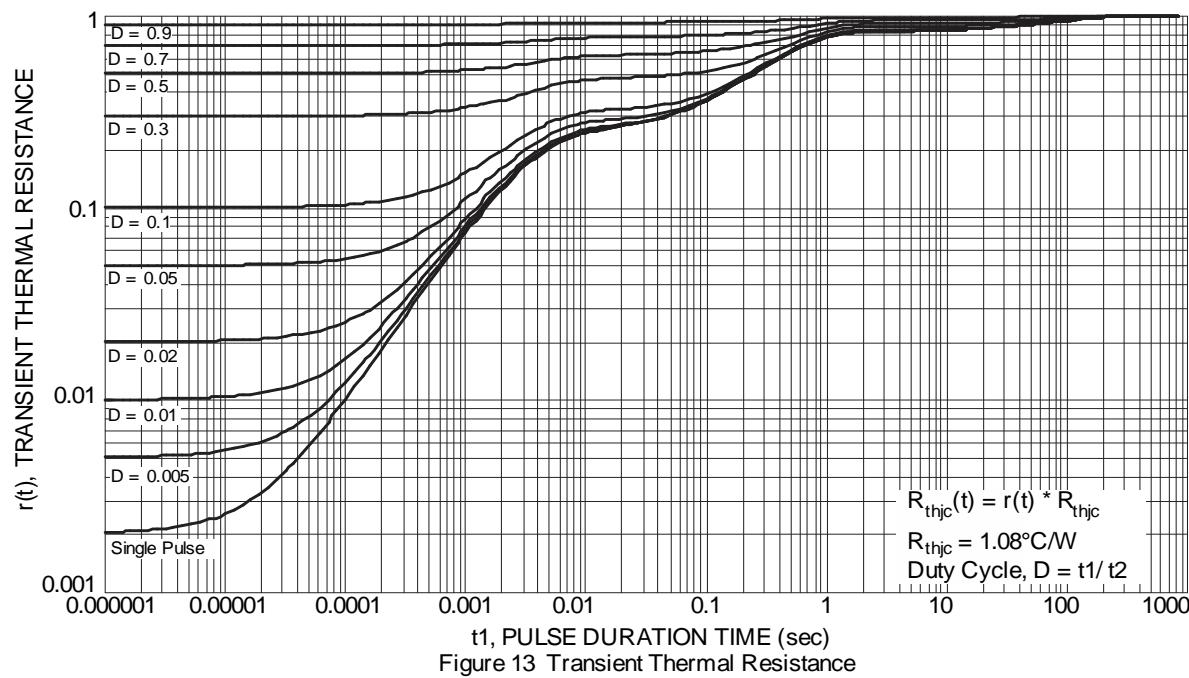
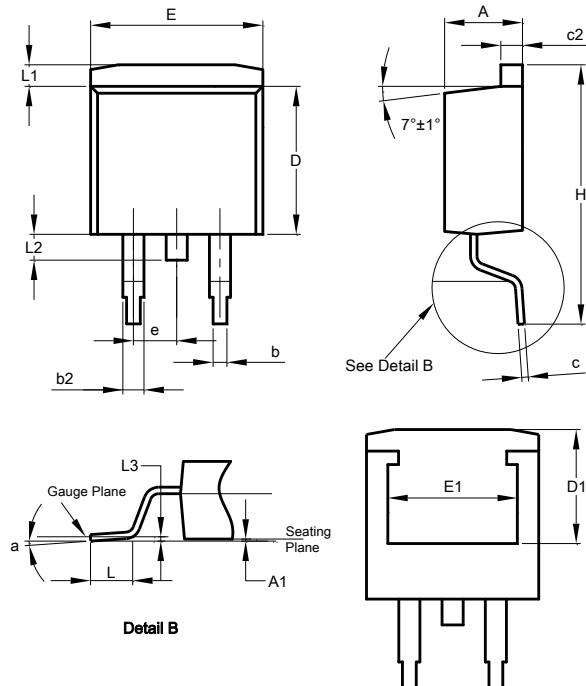


Figure 13 Transient Thermal Resistance

## Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

TO263AB (D2PAK)

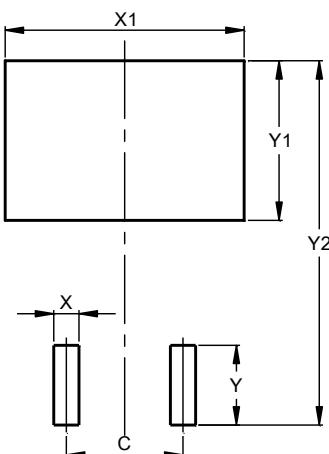


TO263AB (D2PAK)			
Dim	Min	Max	Typ
A	4.07	4.82	—
A1	0.00	0.25	—
b	0.51	0.99	—
b2	1.15	1.77	—
c	0.356	0.73	—
c2	1.143	1.65	—
D	8.39	9.65	—
D1	6.55	6.95	—
e	2.54	2.54 TYP	—
E	9.66	10.66	—
E1	6.23	8.23	—
H	14.61	15.87	—
L	1.78	2.79	—
L1	—	1.67	—
L2	—	1.77	—
L3	—	—	0.254
a	0°	8°	—
All Dimensions in mm			

## Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

TO263AB (D2PAK)



Dimensions	Value (in mm)
C	5.08
X	1.10
X1	10.41
Y	3.50
Y1	7.01
Y2	15.99

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